

# **Supporting Information**

## **Enhancing the Long-Term Photoelectrochemical Performance of TiO<sub>2</sub>/Si Photocathodes by Coating of Ti-Doped Mesoporous Hematite**

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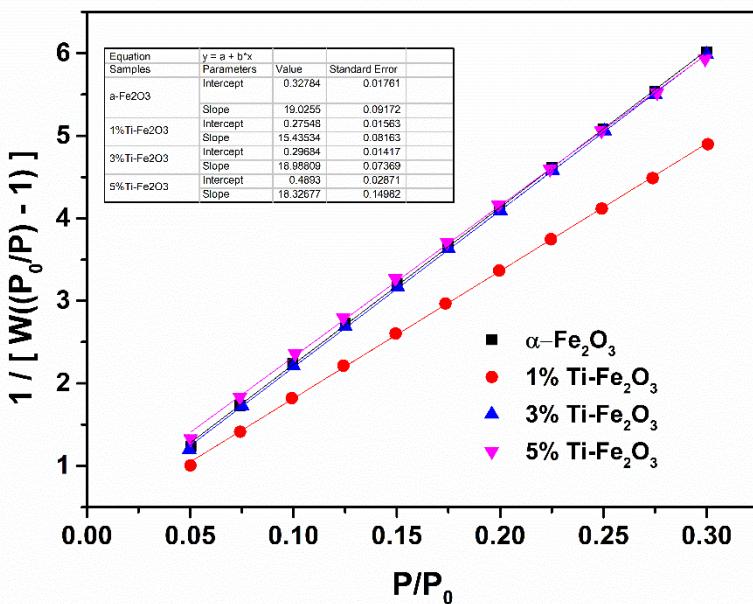


Figure S1. Linear BET plots of  $1/[W(P_0/P) - 1]$  vs.  $P/P_0$  for each sample.

The BET specific surface areas ( $S$ ) are calculated from the isotherms in the  $P/P_0$  range of 0.05 to 0.30 using the Brunauer-Emmett-Teller (BET) equation:

$$\frac{1}{W\left(\frac{P_0}{P}\right) - 1} = \frac{1}{W_m C} + \frac{C - 1}{W_m C} \left(\frac{P}{P_0}\right)$$

$$S = \frac{W_m N A_{cs}}{M}$$

where,  $W$  is the weight of gas adsorbed at a relative pressure,  $P/P_0$ , and  $W_m$  is the weight of adsorbate constituting a monolayer of surface coverage. The BET  $C$  constant, is related to the energy of adsorption in the first adsorbed layer and consequently its value is an indication of the magnitude of the adsorbent/adsorbate interactions.  $N$  is Avogadro's number and  $M$  is the molar mass of nitrogen.  $A_{cs}$  is the cross-sectional area for nitrogen, which is  $16.2 \text{ \AA}^2$ .

Figure S1 shows linear BET plots of  $1/[W(P_0/P) - 1]$  vs.  $P/P_0$  for each sample. The weight of a monolayer of adsorbate  $W_m$  and  $C$  can be obtained from the slope  $b$  and intercept  $a$  of the BET plot. The calculated results are shown in Table S1.

Table S1. A summary on fitting parameters and results for linear BET plots.

Sample	Slope	Intercept	Correlation coefficient, $r$	C constant	BET specific surface area ( $\text{m}^2/\text{g}$ )
$\alpha\text{-Fe}_2\text{O}_3$	19.026	0.3278	0.9999	59.036	180
1%Ti- $\text{Fe}_2\text{O}_3$	15.435	0.2755	0.9999	57.024	222
3%Ti- $\text{Fe}_2\text{O}_3$	18.988	0.2968	0.9999	64.968	181
5%Ti- $\text{Fe}_2\text{O}_3$	18.327	0.4893	0.9997	38.454	185

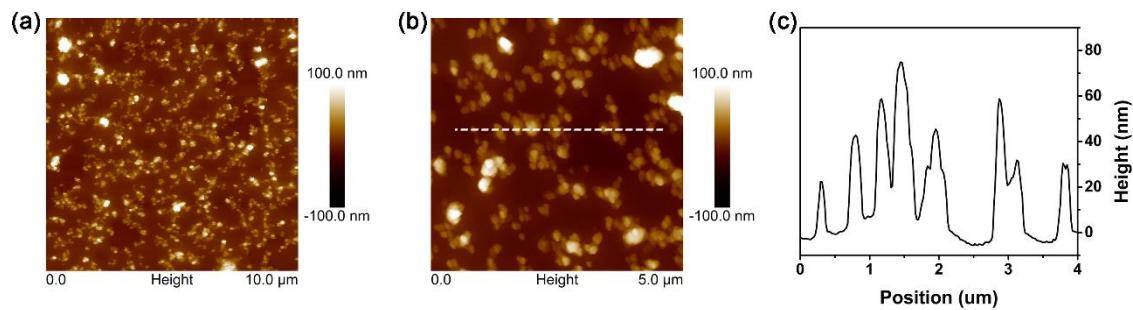


Figure S2. (a-b) AFM images of 3% Ti- $\text{Fe}_2\text{O}_3/\text{TiO}_2/\text{Si}$ . (c) Height profile derives from the line scan of (b).

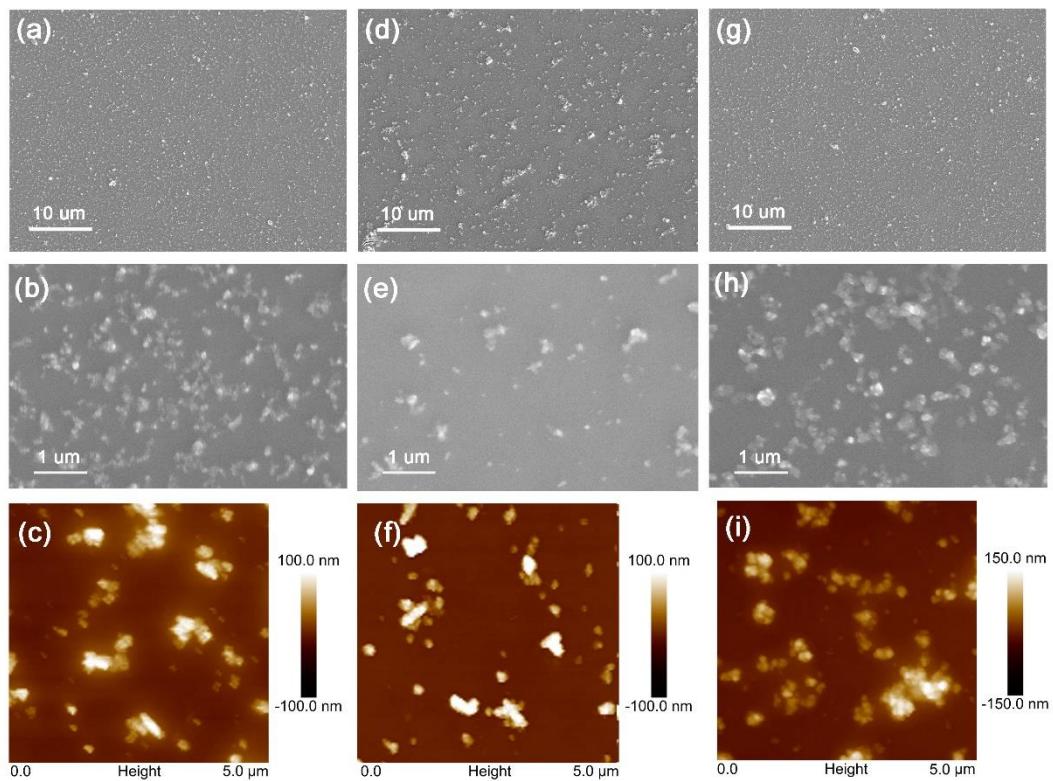


Figure S3. SEM images (a-b)  $\alpha\text{-Fe}_2\text{O}_3/\text{TiO}_2/\text{Si}$ , (d-e) 1% Ti- $\text{Fe}_2\text{O}_3/\text{TiO}_2/\text{Si}$ , and (g-h) 5% Ti- $\text{Fe}_2\text{O}_3/\text{TiO}_2/\text{Si}$ . AFM images of (c)  $\alpha\text{-Fe}_2\text{O}_3/\text{TiO}_2/\text{Si}$ , (f) 1% Ti- $\text{Fe}_2\text{O}_3/\text{TiO}_2/\text{Si}$ , and (i) 5% Ti- $\text{Fe}_2\text{O}_3/\text{TiO}_2/\text{Si}$ .

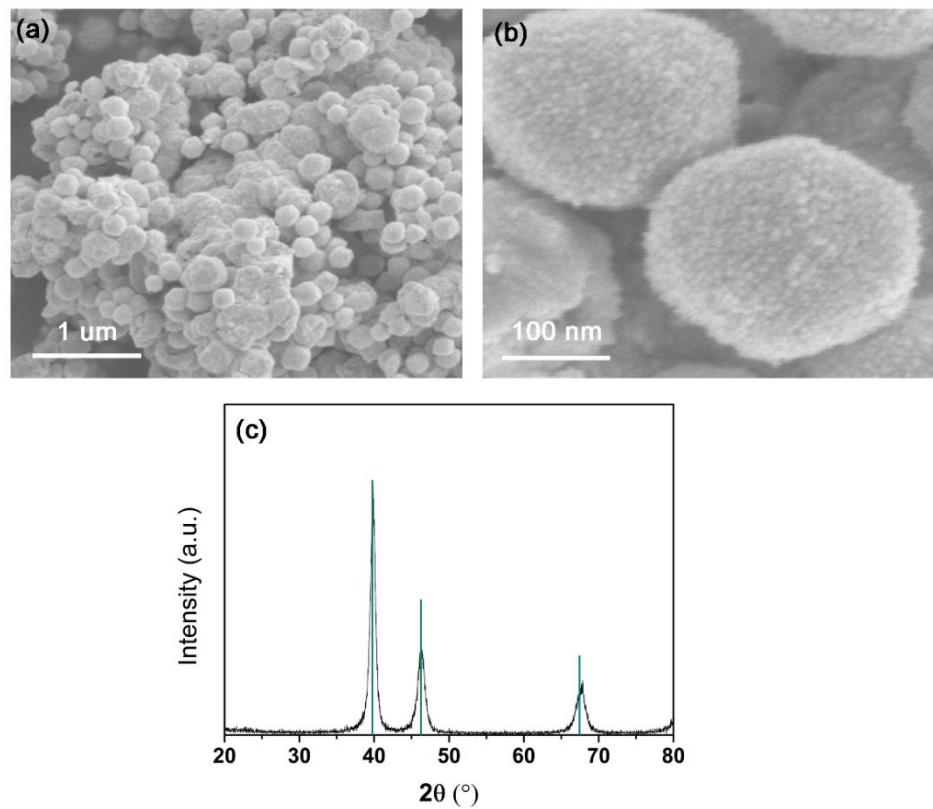


Figure S4. (a-b) SEM images of mesoporous Pt. (c) XRD pattern of mesoporous Pt.

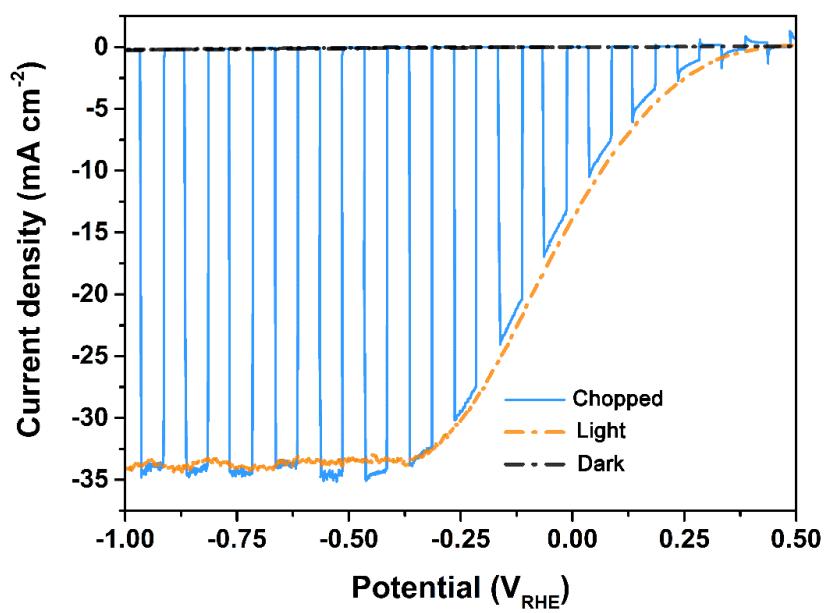


Figure S5.  $I-V$  curves of 3% Ti- $\text{Fe}_2\text{O}_3/\text{TiO}_2/\text{Si}$  in dark, under illumination, and under chopped light.

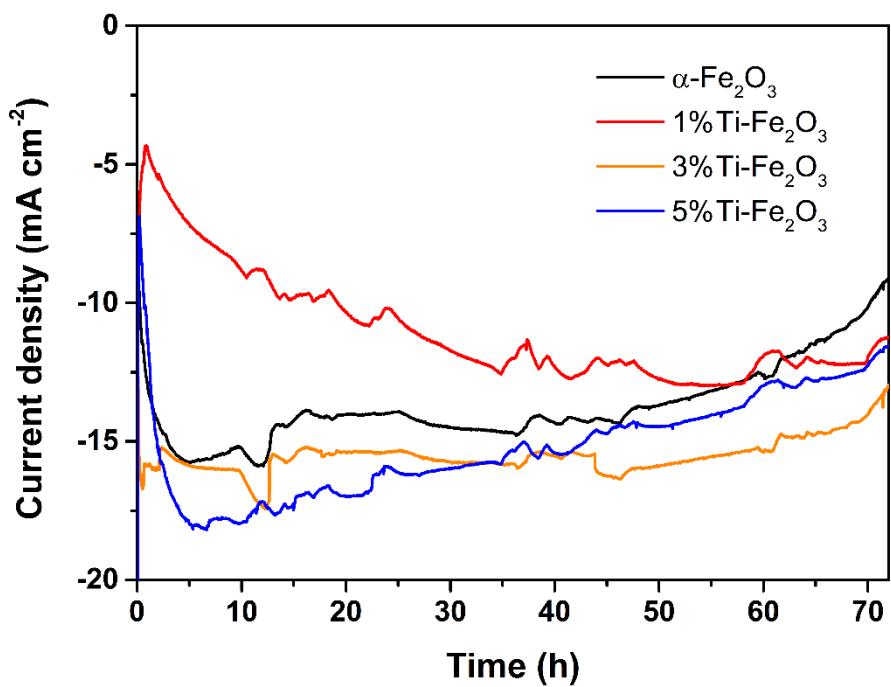


Figure S6. Electrochemical HER stability of  $\alpha\text{-Fe}_2\text{O}_3$ , 1% Ti- $\text{Fe}_2\text{O}_3$ , 3% Ti- $\text{Fe}_2\text{O}_3$ , and 5% Ti- $\text{Fe}_2\text{O}_3$  at  $-0.3\text{ V}_{\text{RHE}}$  in 1.0 M KOH. The powders were coated on carbon paper with the adhesion of nafion solution.

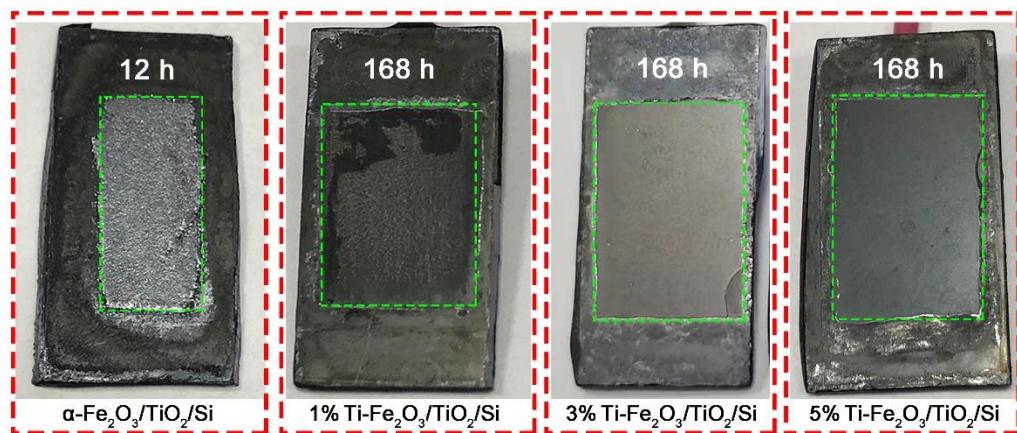


Figure S7. Optical photographs of the  $\alpha\text{-Fe}_2\text{O}_3/\text{TiO}_2/\text{Si}$  and Ti- $\text{Fe}_2\text{O}_3/\text{TiO}_2/\text{Si}$  after stability test, respectively. The regions of green boxes are the test areas.

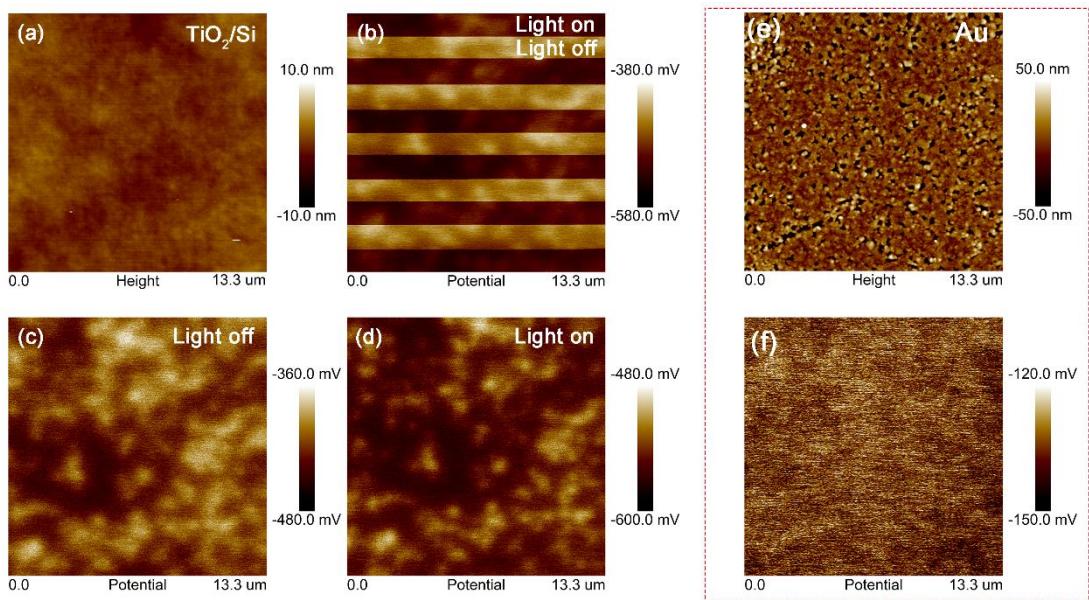


Figure S8. (a-d) AFM image and the corresponding  $V_{\text{CPD}}$  of  $\text{TiO}_2/\text{Si}$ . (e-f) AFM image and the corresponding  $V_{\text{CPD}}$  mapping of Au film.

Table S2. A survey on the PEC performance based on Si from recent literature.

Photocathode	Substrate	Electrolyte	Onset potential (V <sub>RHE</sub> )	<i>j</i> (mA cm <sup>-2</sup> ) (0 V <sub>RHE</sub> )	Stability (h)	Ref.
3% Ti-Fe <sub>2</sub> O <sub>3</sub> /TiO <sub>2</sub> /Si	p-Si	1.0 M KOH	0.33 (-1 mA cm <sup>-2</sup> )	-13.9	168	This work
1% Ti-Fe <sub>2</sub> O <sub>3</sub> /TiO <sub>2</sub> /Si			0.23 (-1 mA cm <sup>-2</sup> )	-5.1	168	
5% Ti-Fe <sub>2</sub> O <sub>3</sub> /TiO <sub>2</sub> /Si			0.21 (-1 mA cm <sup>-2</sup> )	-9.4	168	
$\alpha$ -Fe <sub>2</sub> O <sub>3</sub> /TiO <sub>2</sub> /Si			0.24 (-1 mA cm <sup>-2</sup> )	-5.1	12	
Pt/TiO <sub>2</sub> /Si			0.39 (-1 mA cm <sup>-2</sup> )	-11	38	
Pd/TiO <sub>2</sub> /Si	Porous p-Si	1.0 M KOH	0.32 (-0.5 mA cm <sup>-2</sup> )	-8.3	100	S1
Si/C/TiO <sub>2</sub> /Ni-Mo	p-Si MP array	1.0 M KOH	0.36 (-0.5 mA cm <sup>-2</sup> )	-18	2	S2
Si/TiO <sub>2</sub> /MoS <sub>2</sub>	Pyramid- shape Si	0.5 M H <sub>2</sub> SO <sub>4</sub>	0.42 (-0.1 mA cm <sup>-2</sup> )	-0.24	8	S3
TiO <sub>2</sub> /NiMoO <sub>4-x</sub> S <sub>x</sub> /TiO <sub>2</sub> /Si	p-Si	0.1 M NaH <sub>2</sub> PO <sub>4</sub>	0.3 (-0.1 mA cm <sup>-2</sup> )	-0.5	<1	S4
a-Si/Fh/Ni	p-i-n a-Si	1.0 M KOH	0.67 (-0.1 mA cm <sup>-2</sup> )	-15.6	2.9	S5
p-Si-TiO <sub>2</sub> -MoS <sub>2</sub> /Rh-P	p-Si	0.5 M H <sub>2</sub> SO <sub>4</sub>	0.43 (-0.1 mA cm <sup>-2</sup> )	-24.1	1	S6
PO-MoWS/2 nm TiO <sub>2</sub> /Si	p-Si micropyramids	0.5 M H <sub>2</sub> SO <sub>4</sub>	0.215 (-1 mA cm <sup>-2</sup> )	-11.5	2.2	S7
Pt/Gr/pyramid Si	pyramid Si	1 M HClO <sub>4</sub>	0.41 (-0.1 mA cm <sup>-2</sup> )	-32.5	30	S8
WP/TiO <sub>2</sub> /Si	p-Si	1.0 M KOH	0.27 (-1 mA cm <sup>-2</sup> )	-15	110	S9
C/ $\alpha$ -Fe <sub>2</sub> O <sub>3</sub> /Si NW	Si nanowires	1 M Na <sub>2</sub> SO <sub>4</sub>	-0.18 (-0.1 mA cm <sup>-2</sup> )	~0	2	S10

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